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TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

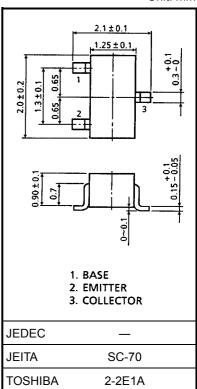
2SC4249

TV VHF RF Amplifier Applications

- High gain: $G_{pe} = 24 dB (typ.) (f = 200 MHz)$
- Low noise: NF = 2.0dB (typ.) (f = 200 MHz)
- Excellent forward AGC characteristics

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	30	V
Collector-emitter voltage	V _{CEO}	30	V
Emitter-base voltage	V _{EBO}	3	V
Collector current	Ι _C	20	mA
Base current	Ι _Β	10	mA
Collector power dissipation	P _C	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.006 g (typ.)

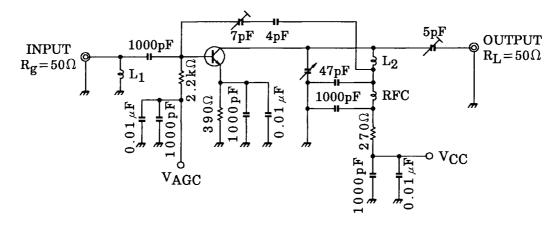
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 25 \text{ V}, \text{ I}_{E} = 0$			100	nA
Emitter cut-off current	I _{EBO}	$V_{EB} = 2 V, I_C = 0$	_		100	nA
Collector-emitter breakdown voltage	V (BR) CEO	$I_{C} = 1 \text{ mA}, I_{B} = 0$	30			V
DC current gain	h _{FE}	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	60	150	300	
Reverse transfer capacitance	C _{re}	$V_{CB} = 10 V, I_E = 0, f = 1 MHz$	_	0.35	0.5	pF
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	400	650		MHz
Power gain	G _{pe}	$V_{CC} = 12 V, V_{AGC} = 1.4 V$	20	24	28	dB
Noise figure	NF	f = 200 MHz (Figure 1)	_	2.0	3.2	dB
AGC voltage (Note)	V _{AGC}	V _{CC} = 12 V, GR = 30dB f = 200 MHz	3.6	4.4	5.1	V

Note: V_{AGC} measured by test circuit shown in Figure 1 when power gain is reduced to 30dB compared that of V_{AGC} at 1.4 V.

Unit: mm

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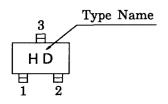


L1: RF coil M-15 T (TOKO Inc.) or equivalent

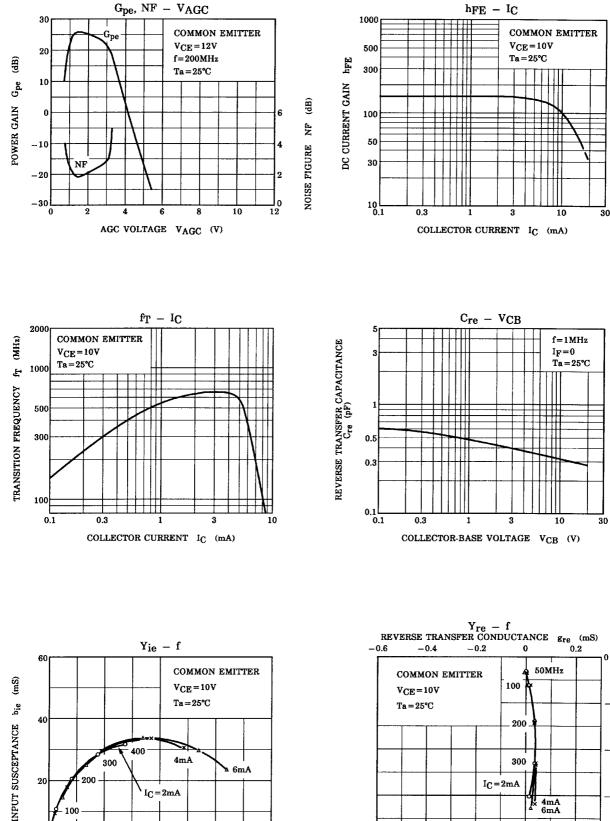
L2: RF coil M-25 T (TOKO Inc.) or equivalent

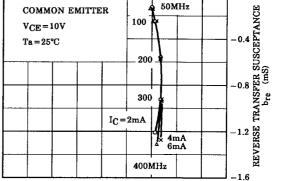


Marking



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2003-03-27

0

4mA

 $I_C = 2mA$

40

INPUT CONDUCTANCE gie (mS)

≥ 6mA

80

60

300

20

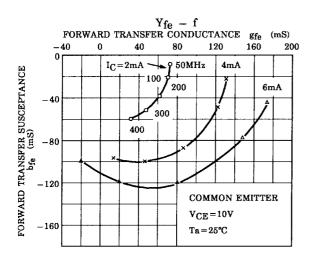
200

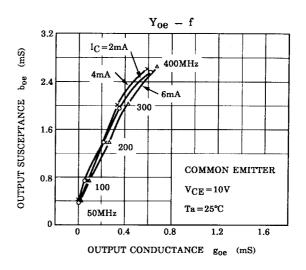
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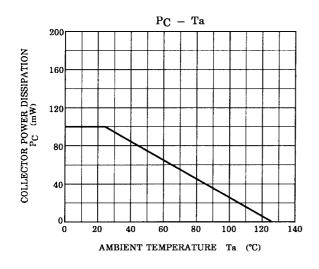
f = 50 MHz

20

0L 0







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